

UNISONIC TECHNOLOGIES CO., LTD

UT2NN03V

Preliminary

2A, 30V N-CHANNEL ENHANCEMENT MODE

DESCRIPTION

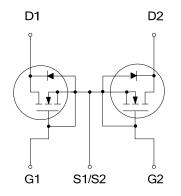
The UTC **UT2NN03V** is N-channel enhancement mode Power MOSFET, designed in serried ranks with fast switching speed, low on-resistance and favorable stabilization.

Used in commercial and industrial surface mount applications and suited for low voltage applications such as DC/DC converters.

FEATURES

- $\label{eq:rescaled_$
- * Fast switching capability
- * Avalanche energy tested
- * Improved dv/dt capability, high ruggedness

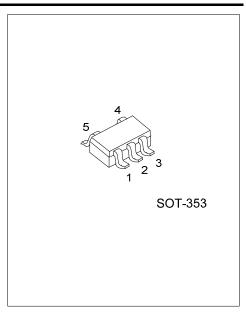
SYMBOL



ORDERING INFORMATION

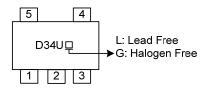
Ordering Number		Deekere	Pin Assignment					Decking	
Lead Free	Halogen Free	Package	1	2	3	4	5	Packing	
UT2NN03VL-AL5-R	UT2NN03VG-AL5-R	SOT-353	G1	S1/S2	G2	D2	D1	Tape Reel	
Note: Pin Assignment: G: Gate S: Source D: Drain									
UT2NN03VG-AL5-R		(1) R. Tape F	Pool						

(1)Packing Type	(1) R: Tape Reel
(2)Package Type	(2) AL5: SOT-353
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free



UT2NN03V

MARKING





ABSOLUTE MAXIMUM RATINGS (T_A =25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATING	UNIT
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±12	V
Continuous Drain Current (Note 3)	I _D	2	А
Pulsed Drain Current (Note 1, 2)	I _{DM}	8	А
Total Power Dissipation (T _A =25°C)	PD	0.2	W
Junction Temperature	TJ	+150	°C
Storage Temperature	T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note)	θја	625	°C/W

Note: Device mounted on FR-4 substrate P_{C} board, 2oz copper, with 1inch square copper plate.

■ ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise specified)

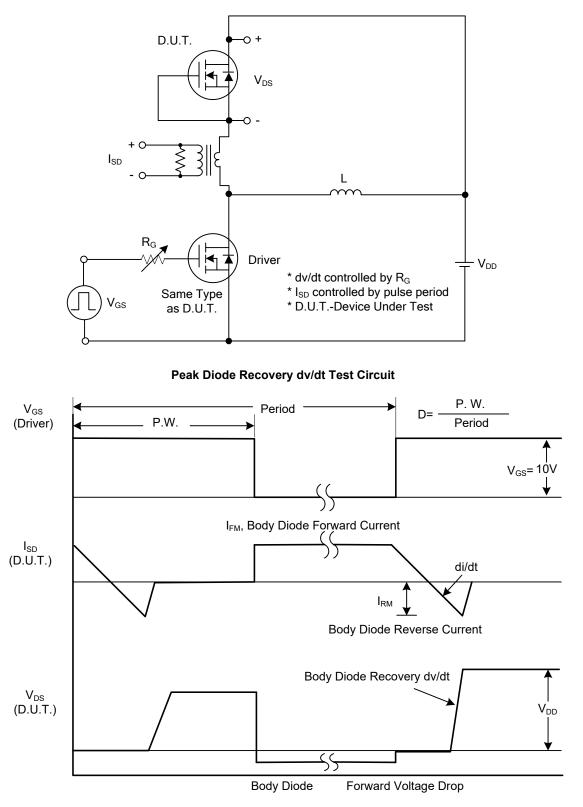
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250µA	30			V
Drain-Source Leakage Current	IDSS	V _{DS} =24V, V _{GS} =0V			1	μA
Gate-Source Leakage Current	lgss	V _{DS} =0V, V _{GS} =±12V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250µA	0.6		1.8	V
		V _{GS} =10V, I _D =1.9A			96	mΩ
Drain-Source On-State Resistance (Note 2)		V _{GS} =4.5V, I _D =1.6A			105	mΩ
	RDS(ON)	V _{GS} =2.5V, I _D =1.2A			128	mΩ
		V _{GS} =1.8V, I _D =0.7A			180	mΩ
DYNAMIC CHARACTERISTICS						
Input Capacitance	CISS			152		рF
Output Capacitance	Coss	V _{DS} =15V,V _{GS} =0V, f=1.0MHz		28		рF
Reverse Transfer Capacitance	Crss			21		рF
SWITCHING CHARACTERISTICS						
Total Gate Charge	Q_{G}			7.2		nC
Gate-Source Charge	Q_{GS}	V _{DS} =24V, V _{GS} =4.5V, I _D =2A (Note 1,2)		1.6		nC
Gate-Drain Charge	Q_{GD}	(Note 1,2)		1.1		nC
Turn-ON Delay Time	t _{D(ON)}			3		ns
Turn-ON Rise Time	t _R	V _{DD} =15V, V _{GS} =10V, I _D =2A,		16		ns
Turn-OFF Delay Time	t _{D(OFF)}	R _G =3Ω (Note 1,2)		19		ns
Turn-OFF Fall Time	t⊨			18		ns
SOURCE- DRAIN DIODE RATINGS AND CH	ARACTERIS	TICS				
Maximum Body-Diode Continuous Current	ls				2	А
Maximum Body-Diode Pulsed Current	I _{SM}				8	А
Drain-Source Diode Forward Voltage (Note 1)	V_{SD}	I _S =2A, V _{GS} =0V			1.2	V

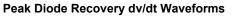
Notes: 1. Pulse Test: Pulse width \leq 300µs, Duty cycle \leq 2%.

2. Essentially independent of operating temperature.



TEST CIRCUITS AND WAVEFORMS



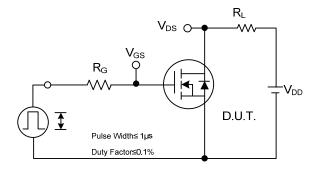


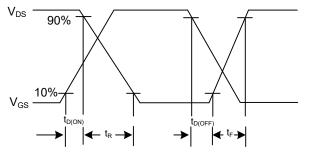


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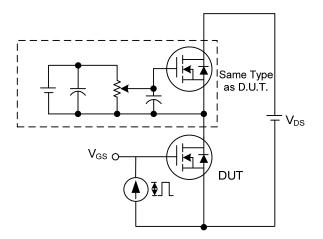
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TEST CIRCUITS AND WAVEFORMS

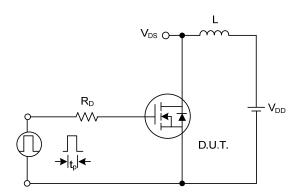




Switching Test Circuit

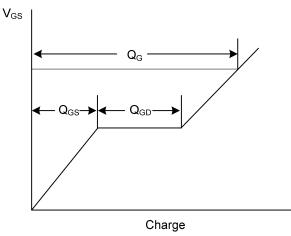


Gate Charge Test Circuit

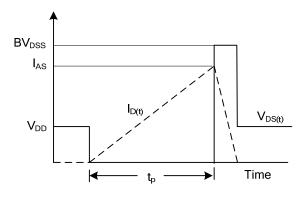


Unclamped Inductive Switching Test Circuit

Switching Waveforms



Gate Charge Waveform



Unclamped Inductive Switching Waveforms



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